

# 2-ph Stepper-motor Driver ICs SPF7211

## Features

- Low output saturation voltage (high-side: 1.5V max.; low-side: 0.8V max.)
- Built-in recovery diode
- Built-in standby function
- Built-in overcurrent and thermal protection circuits and low voltage input shutoff function
- Built-in overload and disconnection detection function

## Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit	Remarks
Main power supply voltage	V <sub>BB</sub>	40	V	
Input voltage	V <sub>IN</sub>	-0.3 to 15	V	V <sub>IN</sub> ≤ V <sub>BB</sub>
Output current	I <sub>O</sub>	±0.8	A	
	I <sub>OPeak</sub>	±1.0	A	T <sub>w</sub> < 1mS
Flag terminal withstand voltage	V <sub>Flag</sub>	7	V	V <sub>Flag</sub> ≤ V <sub>BB</sub>
Flag terminal current	I <sub>Flag</sub>	3	mA	
Detect voltage	V <sub>Rs</sub>	-2 to 2	V	
Power dissipation	P <sub>D</sub>	4.1	W	For T <sub>a</sub> = 25°C *1
		39		For T <sub>c</sub> (T <sub>tab</sub> ) = 25°C
Junction temperature	T <sub>j</sub>	150	°C	
Operating temperature	Top	-40 to 110	°C	
Storage temperature	T <sub>stg</sub>	-40 to 150	°C	

Note: \*1: With glass epoxy + copper foil board (size 5.0 × 7.4cm; t: glass epoxy = 1.6mm/copper foil = 18μm)

## Recommended Operation Range

Parameter	Symbol	Ratings	Unit	Remarks
Main power supply voltage	V <sub>BB</sub>	6 to 18	V	
Input voltage	V <sub>IN</sub>	-0.3 to 7.0	V	V <sub>IN</sub> ≤ V <sub>BB</sub>
Output current	I <sub>O</sub>	±0.5	A	Continuous
Flag terminal withstand voltage	V <sub>Flag</sub>	0 to 7.0	V	V <sub>Flag</sub> ≤ V <sub>BB</sub>
Flag terminal current	I <sub>Flag</sub>	0 to 1.0	mA	
Detect voltage	V <sub>Rs</sub>	-1 to 1	V	
Operating temperature	Top	-40 to 110	°C	

## Electrical Characteristics

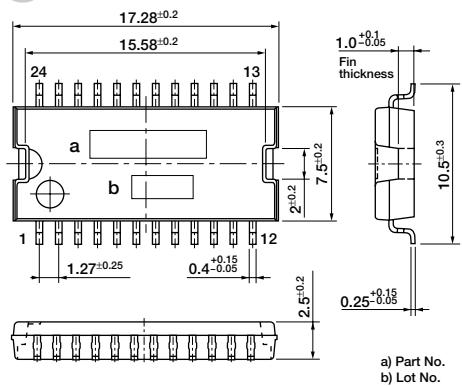
Parameter	Symbol	Ratings			Unit	Conditions	
		min	typ	max			
Main power supply current	I <sub>BB</sub>		50	mA	In ordinary operation (no load)		
	I <sub>BBs</sub>		50	μA	At sleep		
Low voltage protection operation voltage	V <sub>UVLO</sub>	3.5	4.5	V			
UVLO hysteresis voltage	V <sub>UVLohys</sub>		0.5	V			
Output leak current	I <sub>oleakL</sub>	-100		μA	V <sub>BB</sub> = 40V, Vo = 0V		
	I <sub>oleakH</sub>		100	μA	V <sub>BB</sub> = Vo = 40V		
	V <sub>satL</sub>		0.5	V	I <sub>O</sub> = 0.5A		
Output saturation voltage	V <sub>satH</sub>		0.8	V	I <sub>O</sub> = 0.8A		
	V <sub>fL</sub>		1.2	V	I <sub>O</sub> = 0.5A		
Recovery diode forward voltage	V <sub>fH</sub>		1.3	V	I <sub>O</sub> = 0.5A		
	V <sub>fGO</sub>	1.2		V	I <sub>O</sub> = 0.5A		
Input terminal	Input voltage	V <sub>IL</sub>		0.8	V		
	V <sub>IH</sub>	2.0		V			
	Hysteresis voltage	V <sub>hys</sub>	0.5	V			
Ph terminal	Input current	I <sub>IL</sub>	-5	5	μA		
	I <sub>IH</sub>	-5		5	μA		
I <sub>xx</sub> , Set terminals	Input current	I <sub>IL</sub>	-30	μA	V <sub>IL</sub> = 0.8V VIH = 2.0V		
	I <sub>IH</sub>	660	700	740	mV	I <sub>x0</sub> = High, I <sub>x1</sub> = High	
		420	450	480	mV	I <sub>x0</sub> = Low, I <sub>x1</sub> = High	
		40	70	90	mV	I <sub>x0</sub> = High, I <sub>x1</sub> = Low	
Oscillation frequency	F <sub>osc</sub>	28.8	48	72	kHz	C <sub>t</sub> = 2200pF ± 20%	
PWM frequency	F <sub>PWM</sub>	14.4	24	36	kHz	C <sub>t</sub> = 2200pF ± 20%	
Ct terminal threshold voltage	V <sub>ctl</sub>	0.5		V			
	V <sub>ctth</sub>	1.5		V			
Ct terminal current	I <sub>ctsink</sub>	720		μA			
	I <sub>ctsouce</sub>	-120		μA			
	V <sub>ocpl</sub>	1.5	3.0	4.2	V	Out voltage	
Overcurrent detection voltage	V <sub>ocph</sub>	V <sub>BB</sub> - 2.5	V <sub>BB</sub> - 2.0	V <sub>BB</sub> - 1.7	V	Out voltage	
	V <sub>ocpl</sub>	1.0		1.85	V	V <sub>BB</sub> = 5.5V	
	V <sub>ocph</sub>	V <sub>BB</sub> - 2.3		V <sub>BB</sub> - 1.5	V	V <sub>BB</sub> = 5.5V	
Open detection voltage	V <sub>open</sub>		-60		mV	Sense voltage	
Flag terminal leak current	I <sub>leakflag</sub>			10	μA	V <sub>Flag</sub> = 7V	
Flag terminal saturation voltage	V <sub>flagL</sub>			0.5	V	I <sub>flag</sub> = 1mA	
Flag terminal current	I <sub>flag</sub>			3	mA		
Set terminal	Response pulse width	T <sub>pw</sub>	10		μs	In ordinary operation	
	T <sub>pws</sub>	100			μs	At sleep	
	Pulse rate	F <sub>clock</sub>	17	24	Hz	C <sub>t</sub> = 2200pF	
	Pulse number	Pulse		256	—		
Flag response time	OCP operation	to <sub>cpl1</sub>	2.5	5.0	10.0	μs	In ordinary operation: C <sub>t</sub> = 2200pF
		to <sub>cpl2</sub>	5.0	10.0	20.0	μs	At switching the phase
		to <sub>cpl3</sub>	5.0	10.0	20.0	μs	When I <sub>xx</sub> shifts from L to H
	Open operation	to <sub>pen1</sub>	2.5	5.0	10.0	μs	In ordinary operation
		to <sub>pen2</sub>	2.5	5.0	10.0	μs	When I <sub>xx</sub> shifts from L to H
		t <sub>onH1</sub>		1.5		μs	
		t <sub>offH1</sub>		1.5		μs	
I/O propagation time	t <sub>onH2</sub>	100			μs		
		t <sub>offH2</sub>	100		μs		
		t <sub>onL1</sub>		2.0		μs	
		t <sub>offL1</sub>		0.5		μs	
		t <sub>onL2</sub>	100		μs		
		t <sub>offL2</sub>	100		μs		
Thermal protection temperature	T <sub>j</sub>	150			°C		
Thermal protection hysteresis	ΔT <sub>j</sub>		20		°C		
Thermal alarm temperature	T <sub>alarm</sub>	120	130	140	°C		
Thermal alarm hysteresis	ΔT <sub>alarm</sub>		20		°C		

Note:

\*1: The Ct terminal threshold voltage and current are the design values. Warranty is based on the oscillation frequency.

\*2: Thermal protection and alarm temperatures are design values.

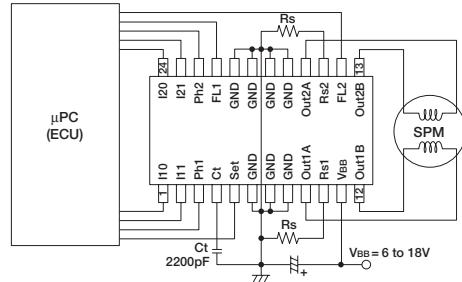
## External Dimensions (unit: mm)



a) Part No.

b) Lot No.

## Standard Circuit Diagram



### Excitation Signal Time Chart

Clock	0	1	2	3	0	1
Ph1	L	H	H	L	L	H
I10, I11	H	L	H	H	H	H
Ph2	L	L	H	H	L	L
I20, I21	H	H	L	H	H	H

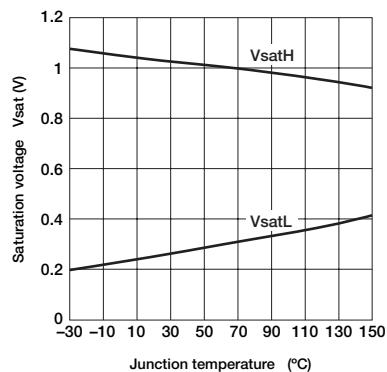
2-phase excitation

\* For the 1 to 2-phase excitation application, switch the Ph signal in the step of 1-ph excitation (ex: turns from high to low).

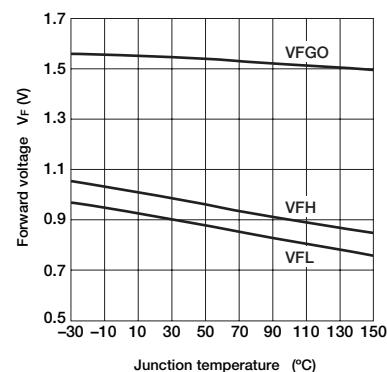
The OPEN detection function is invalid except in this sequence.

## Electrical Characteristics

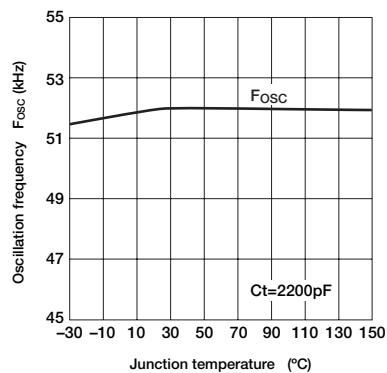
■ Vsat Temperature Characteristics ( $I_o=0.5A$ )



■ Diode  $V_F$  Characteristics ( $I_F=0.5A$ )



■ OSC Temperature Characteristics



■ Ta-Pd Characteristics

